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# MCH3375

## Power MOSFET –30V, 295mΩ, –1.6A, Single P-Channel

### Features

- On-Resistance  $R_{DS(on)1}=227m\Omega$  (typ)
- 4V Drive
- High Speed Switching and Low Loss
- Pb-Free, Halogen Free and RoHS Compliance

### Specifications

#### Absolute Maximum Ratings at $T_a = 25^\circ C$

Parameter	Symbol	Value	Unit
Drain to Source Voltage	$V_{DSS}$	–30	V
Gate to Source Voltage	$V_{GSS}$	$\pm 20$	V
Drain Current (DC)	$I_D$	–1.6	A
Drain Current (Pulse) $PW \leq 10\mu s$ , duty cycle $\leq 1\%$	$I_{DP}$	–6.4	A
Power Dissipation When mounted on ceramic substrate ( $900mm^2 \times 0.8mm$ )	$P_D$	0.8	W
Junction Temperature	$T_J$	150	$^\circ C$
Storage Temperature	$T_{stg}$	–55 to +150	$^\circ C$

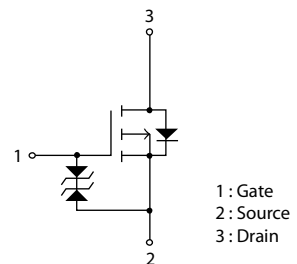
This product is designed to "ESD immunity < 200V\*", so please take care when handling.  
\* Machine Model

#### Thermal Resistance Ratings

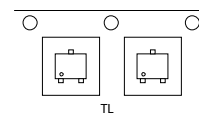
Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate ( $900mm^2 \times 0.8mm$ )	$R_{\theta JA}$	156.25	$^\circ C/W$

$V_{DSS}$	$R_{DS(on)}$ Max	$I_D$ Max
–30V	295mΩ@ –10V	–1.6A
	523mΩ@ –4.5V	
	609mΩ@ –4V	

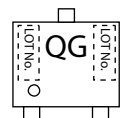
#### Electrical Connection P-Channel



#### Packing Type: TL



#### Marking



Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

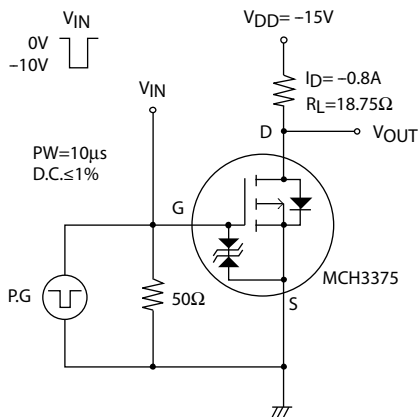
# MCH3375

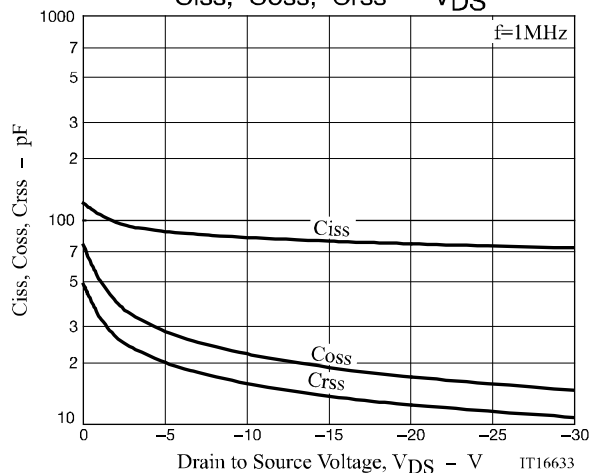
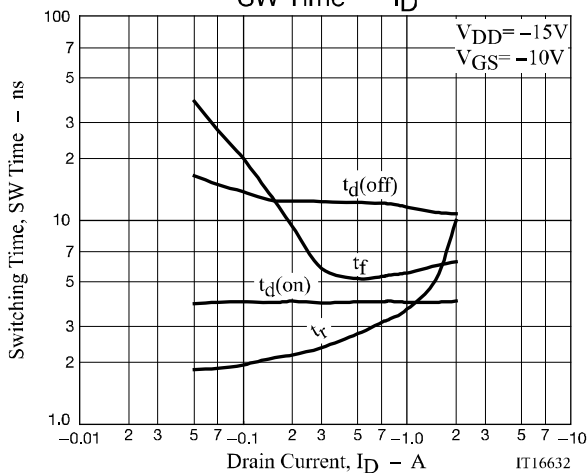
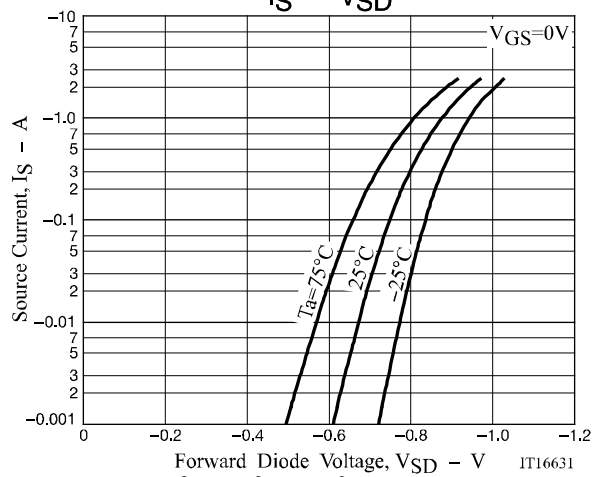
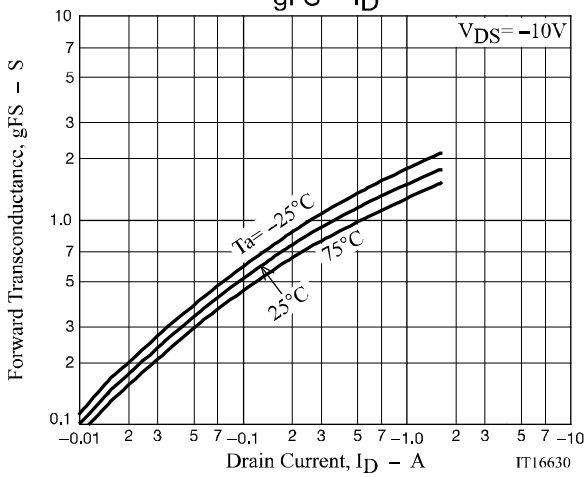
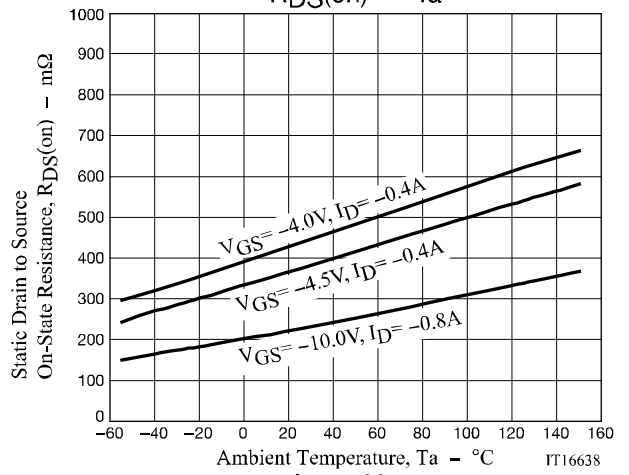
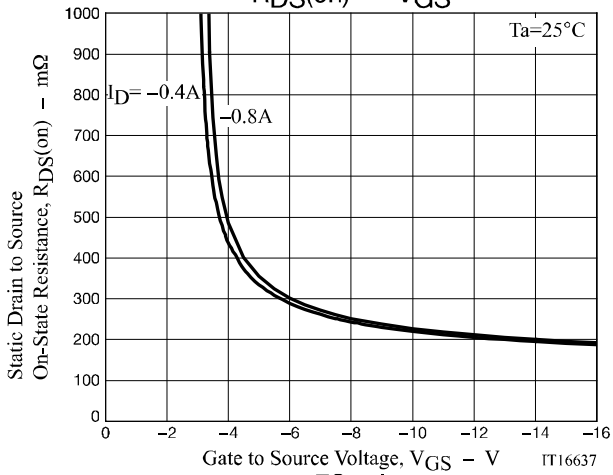
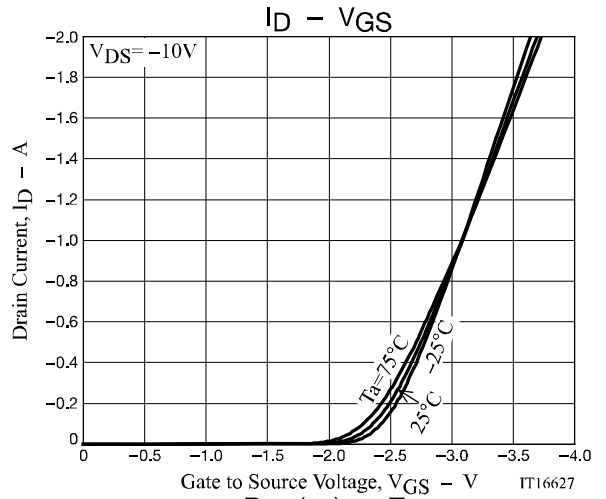
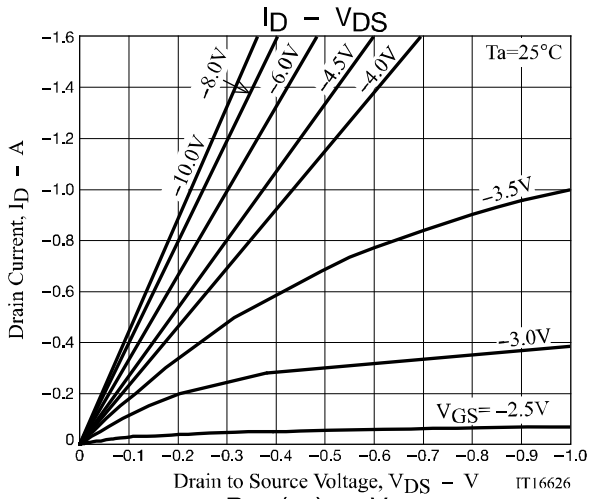
## Electrical Characteristics at $T_a = 25^\circ\text{C}$

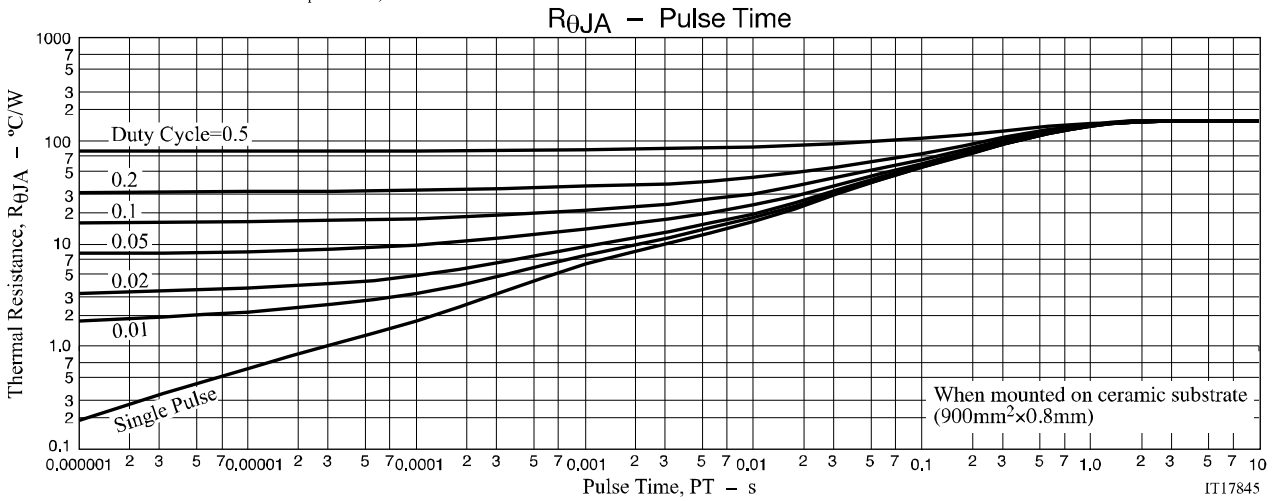
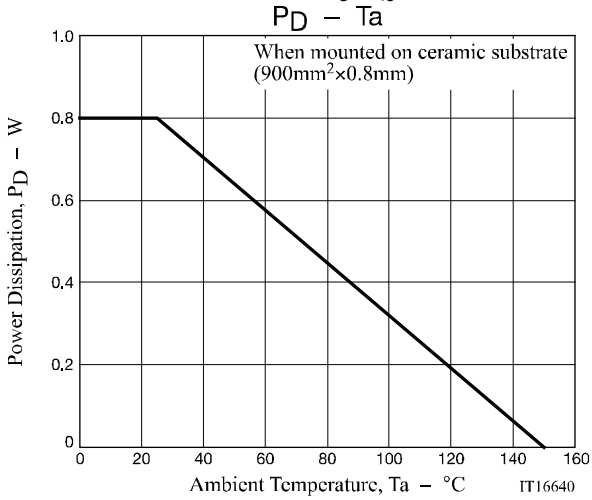
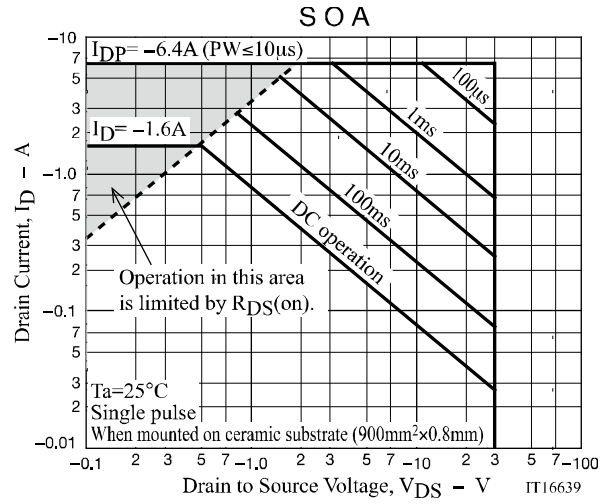
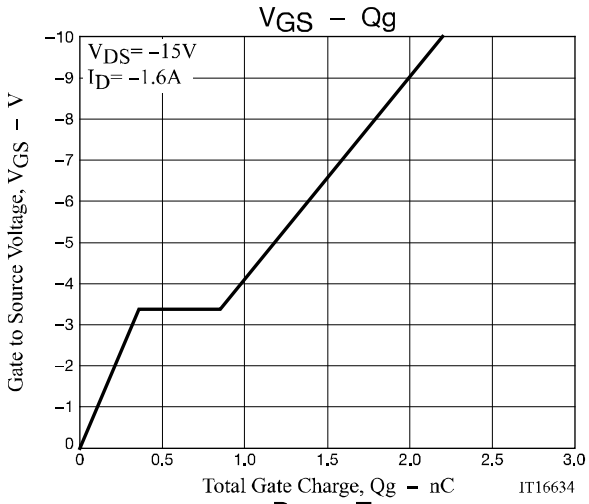
Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1\text{mA}$ , $V_{GS} = 0\text{V}$	-30			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -30\text{V}$ , $V_{GS} = 0\text{V}$			-1	$\mu\text{A}$
Gate to Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 16\text{V}$ , $V_{DS} = 0\text{V}$			$\pm 10$	$\mu\text{A}$
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = -10\text{V}$ , $I_D = -1\text{mA}$	-1.2		-2.6	V
Forward Transconductance	$g_{FS}$	$V_{DS} = -10\text{V}$ , $I_D = -0.8\text{A}$		1.3		S
Static Drain to Source On-State Resistance	$R_{DS(on)1}$	$I_D = -0.8\text{A}$ , $V_{GS} = -10\text{V}$		227	295	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D = -0.4\text{A}$ , $V_{GS} = -4.5\text{V}$		374	523	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D = -0.4\text{A}$ , $V_{GS} = -4\text{V}$		435	609	$\text{m}\Omega$
Input Capacitance	$C_{iss}$	$V_{DS} = -10\text{V}$ , $f = 1\text{MHz}$		82		pF
Output Capacitance	$C_{oss}$			22		pF
Reverse Transfer Capacitance	$C_{rss}$			16		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		4.0		ns
Rise Time	$t_r$			3.3		ns
Turn-OFF Delay Time	$t_{d(off)}$			12		ns
Fall Time	$t_f$			5.4		ns
Total Gate Charge	$Q_g$		$V_{DS} = -15\text{V}$ , $V_{GS} = -10\text{V}$ , $I_D = -1.6\text{A}$		2.2	
Gate to Source Charge	$Q_{gs}$			0.36		nC
Gate to Drain "Miller" Charge	$Q_{gd}$			0.49		nC
Forward Diode Voltage	$V_{SD}$	$I_S = -1.6\text{A}$ , $V_{GS} = 0\text{V}$		-0.9	-1.5	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## Switching Time Test Circuit







# MCH3375

## Package Dimensions

MCH3375-TL-H / MCH3375-TL-W

### MCPH3

CASE 419AQ

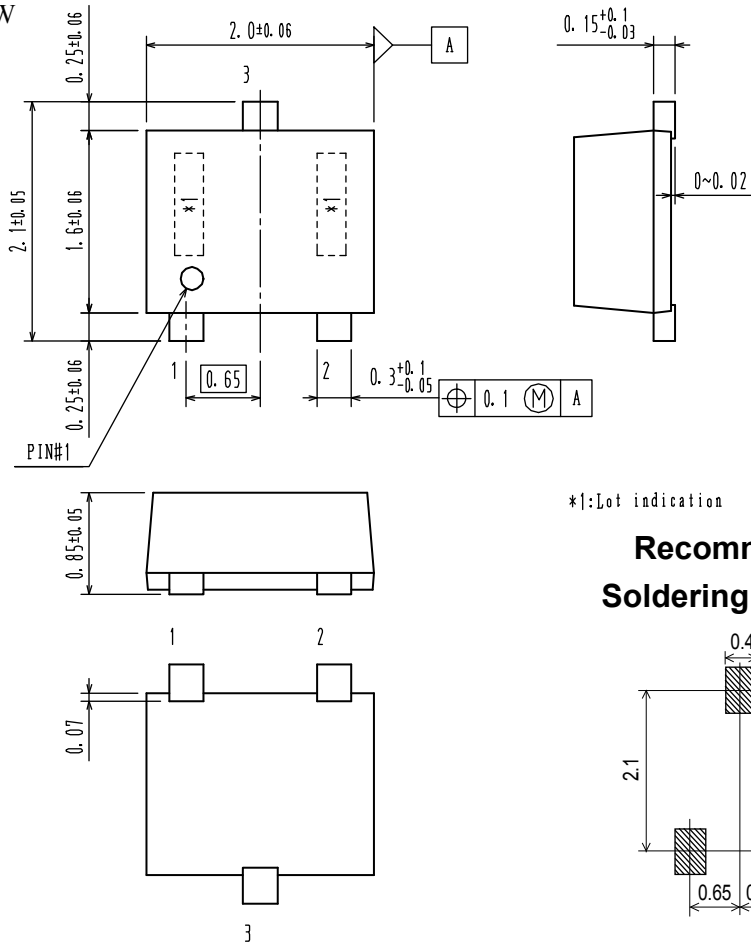
ISSUE O

Unit : mm

1 : Gate

2 : Source

3 : Drain



\*|:Lot indication

## Recommended Soldering Footprint

## ORDERING INFORMATION

Device	Package	Shipping	Note
MCH3375-TL-H	MCPH3 SC-70,SOT-323	3,000 pcs. / reel	Pb-Free and Halogen Free
MCH3375-TL-W			

Note on usage : Since the MCH3375 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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